

# TRIAC(Through Hole / Isolated)

# TMG12CQ60F 5

(T<sub>j</sub>=150°C)

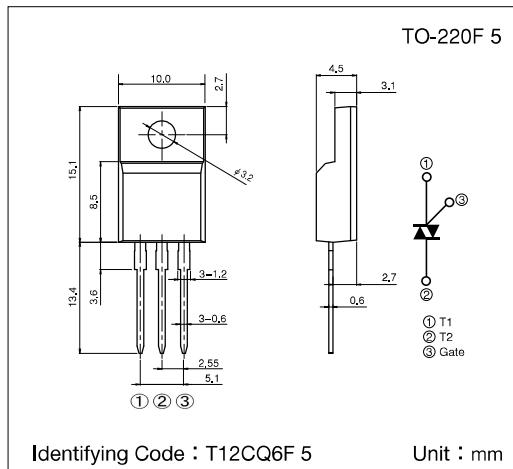
SanRex Triac TMG12CQ60F 5 is designed for full wave AC control applications. It can be used as an ON/OFF function or for phase control operation.

## Typical Applications

- Home Appliances : Washing Machines, Vacuum Cleaners, Rice Cookers, Micro Wave Ovens, Hair Dryers, other control applications
- Industrial Use : SMPS, Copier Machines, Motor Controls, Dimmer, SSR, Heater Controls, Vending Machines, other control applications

## Features

- I<sub>T(RMS)</sub>=12A
- High Surge Current
- Low Voltage Drop



Identifying Code : T12CQ6F 5

Unit : mm

## Maximum Ratings

(T<sub>j</sub>=25°C unless otherwise specified)

Symbol	Item	Reference	Ratings		Unit
V <sub>DRM</sub>	Repetitive Peak Off-State Voltage		600		V
I <sub>T(RMS)</sub>	R.M.S. On-State Current	T <sub>c</sub> =107°C	12		A
I <sub>SM</sub>	Surge On-State Current	One cycle, 50Hz/60Hz, Peak value, non-repetitive	119/130		A
I <sup>2</sup> t	I <sup>2</sup> t (for fusing)		71		A <sup>2</sup> s
P <sub>GM</sub>	Peak Gate Power Dissipation		5		W
P <sub>G(AV)</sub>	Average Gate Power Dissipation		0.5		W
I <sub>GM</sub>	Peak Gate Current		2		A
V <sub>GM</sub>	Peak Gate Voltage		10		V
V <sub>ISO</sub>	Isolation Breakdown Voltage (R.M.S.)	A.C. 1minute	1500		V
T <sub>j</sub>	Operating Junction Temperature		-40~+150		°C
T <sub>stg</sub>	Storage Temperature		-40~+150		°C
	Mass		2		g

## Electrical Characteristics

Symbol	Item	Reference	Ratings			Unit
			Min.	Typ.	Max.	
I <sub>DRM</sub>	Repetitive Peak Off-State Current	V <sub>D</sub> =V <sub>DRM</sub> , Single phase, half wave, T <sub>j</sub> =150°C			2	mA
V <sub>TM</sub>	Peak On-State Voltage	I <sub>T</sub> =20A, Inst. measurement			1.4	V
I <sub>GT1</sub> <sup>+</sup> 1	Gate Trigger Current	V <sub>D</sub> =6V, R <sub>L</sub> =10Ω			30	mA
I <sub>GT1</sub> <sup>+</sup> 2					30	
I <sub>GT3</sub> <sup>+</sup> 3					—	
I <sub>GT3</sub> <sup>+</sup> 4					30	
V <sub>GT1</sub> <sup>+</sup> 1	Gate Trigger Voltage	V <sub>D</sub> =6V, R <sub>L</sub> =10Ω			1.5	V
V <sub>GT1</sub> <sup>+</sup> 2					1.5	
V <sub>GT3</sub> <sup>+</sup> 3					—	
V <sub>GT3</sub> <sup>+</sup> 4					1.5	
V <sub>GD</sub>	Non-Trigger Gate Voltage	T <sub>j</sub> =150°C, V <sub>D</sub> =1/2V <sub>DRM</sub>	0.1			V
(dv/dt) <sub>C</sub>	Critical Rate of Rise of Off-State Voltage at Commutation	T <sub>j</sub> =150°C, (di/dt) <sub>C</sub> =-6A/ms, V <sub>D</sub> =2/3V <sub>DRM</sub>	5			V/μs
I <sub>H</sub>	Holding Current				20	mA
R <sub>th</sub>	Thermal Resistance	Junction to case			3.3	°C/W

Trigger mode of the triac

